## NSN 5961-00-098-8550

Transistor - Page 1 of 1



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Metal OveralLength: Between 0.240 inches and 0.260 inches Terminal Length: 1.500 inches Overall Diameter: Between 0.335 inches and 0.370 inches Internal Configuration: Junction contact Electrode Internally-electrically Connected To Case: Collector Mounting Method: Terminal Terminal Terminal Terminal Circle Diameter: 0.200 inches Features Provided: Hermetically sealed case Semiconductor Material: Silicon Vottage Rating In Votts Per Characteristic: 1.0 watts small-signal input power, common-collector absolute Maximu Operating Tempurature Per Measurement Point: 200.0 degrees celsus junction Special Features: Junction pattern arrangement: pnp Terminal Type And Quantiy: 3 unisulated wire lead Sheff Life: Na	Motol	
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